



**Product data sheet** 

#### **1. General description**

AC Thyristor power switch in a TO92 plastic package with self-protective capabilities against low and high energy transients

#### 2. Features and benefits

- Exclusive negative gate triggering
- Full cycle AC conduction
- Very high noise immunity
- · Remote gate separates the gate driver from the effects of the load current
- · Safe clamping of low energy over-voltage transients
- · Self-protective turn-on during high energy voltage transients
- High voltage capability

#### 3. Applications

- Fan motor circuits
- Pump motor circuits
- · Lower-power highly inductive, resistive and safety loads

#### 4. Quick reference data

Table 1. Q	uick reference data		 			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating					
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	-	800	V
$\mathbf{I}_{\mathrm{T(RMS)}}$	RMS on-state current	full sine wave; T <sub>lead</sub> ≤ 75 °C; <u>Fig 1</u> ; <u>Fig 2</u> ; <u>Fig 3</u>	-	-	0.8	А
Static ch	aracteristics					
I <sub>GT</sub>	gate trigger current	$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	1	-	10	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; LD- G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	1	-	10	mA

# 5. Pinning information

Table 2.	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	СМ	common		LD I
2	G	gate		G-O
3	LD	load	() (	CM 001aaj924

# 6. Ordering information

Table 3. Orderin	g informat	tion				
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
ACT108-800E	TO92	ACT108-800EEP	Bulk, 412	1000	SOT54 Straight lead	14-Nov-2013
ACT108-800E	TO92	ACT108-800EQP	Reel, 116	2000	SOT54 wide pitch	14-Nov-2013
ACT108-800E	TO92	ACT108-800EML	Ammo, 126	2000	SOT54 wide pitch	14-Nov-2013

## 7. Marking

Table 4.	Marking	codes
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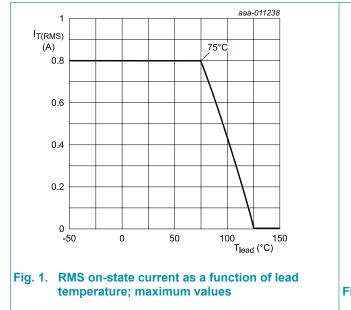
Type number	Marking codes
ACT108-800E	108-8E

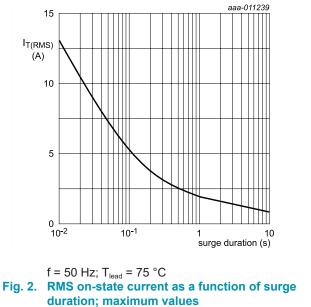
## 8. Limiting values

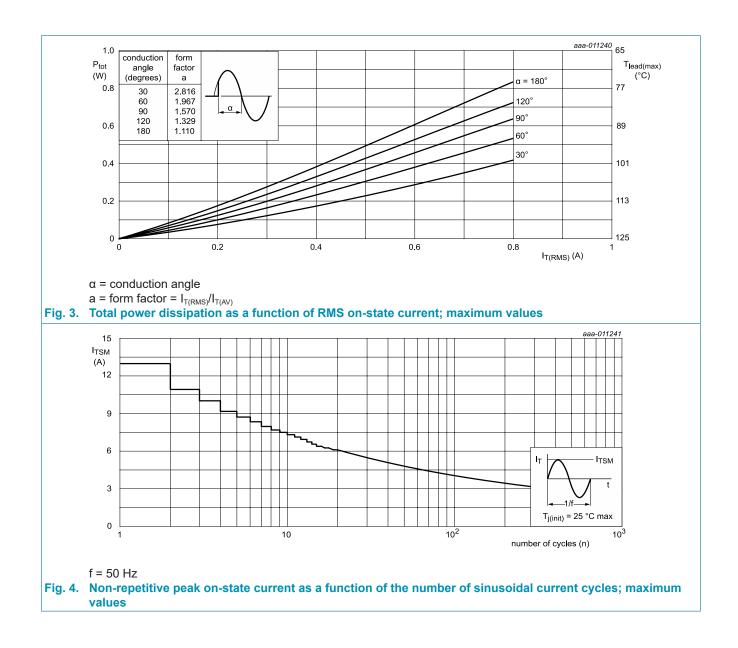
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	800	V
$\mathbf{I}_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; T <sub>lead</sub> ≤ 75 °C; <u>Fig 1; Fig 2</u> ; <u>Fig 3</u>	-	0.8	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 20 ms; Fig 4; Fig 5	-	13	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	14.3	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	0.84	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 20 mA	-	100	A/µs
I <sub>GM</sub>	peak gate current	t <sub>p</sub> = 20 us	-	1	А
V <sub>GM</sub>	peak gate voltage	positive applied gate voltage	-	15	V
P <sub>G(AV)</sub>	average gate power	over any 20ms period	-	0.1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
$V_{PP}$	peak pulse voltage	$T_j = 25^{\circ}C$ ; non-repetitive, off-state; ten pulses on each voltage polarity; 20s or more between successive pulses; Fig 6	-	2.5	kV

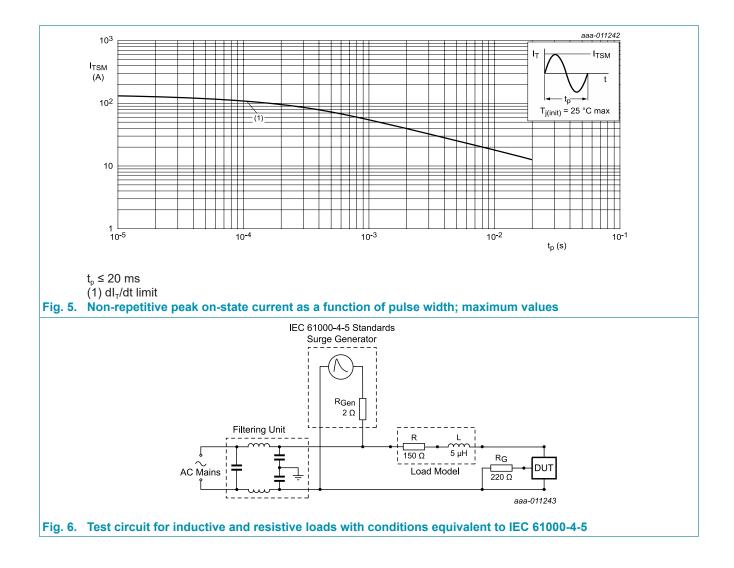






# ACT108-800E

AC Thyristor power switch



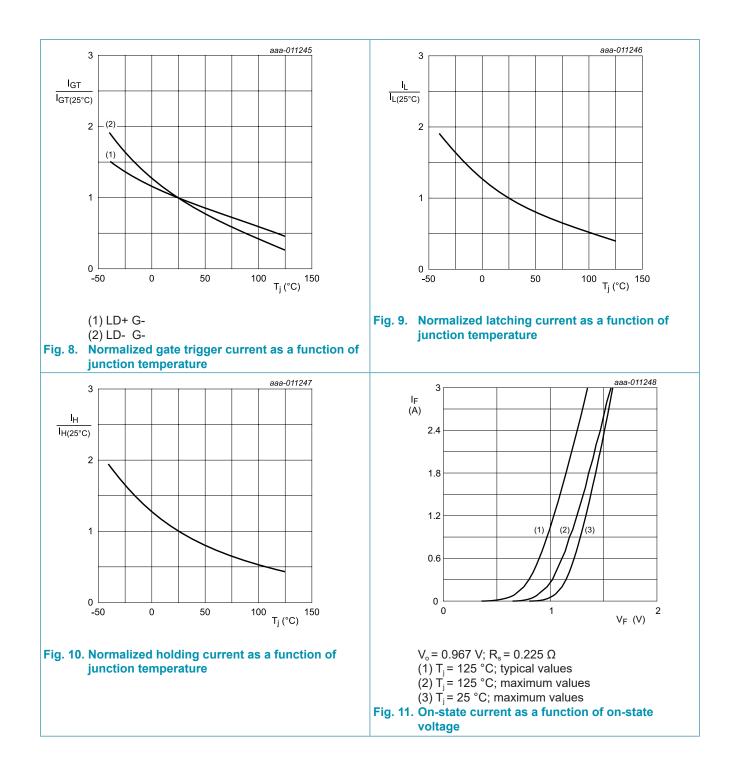
## 9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	full cycle with heatsink compound; Fig. 7	-	-	60	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	full cycle; printed-circuit board mounted; lead length 4mm	-	150	-	K/W

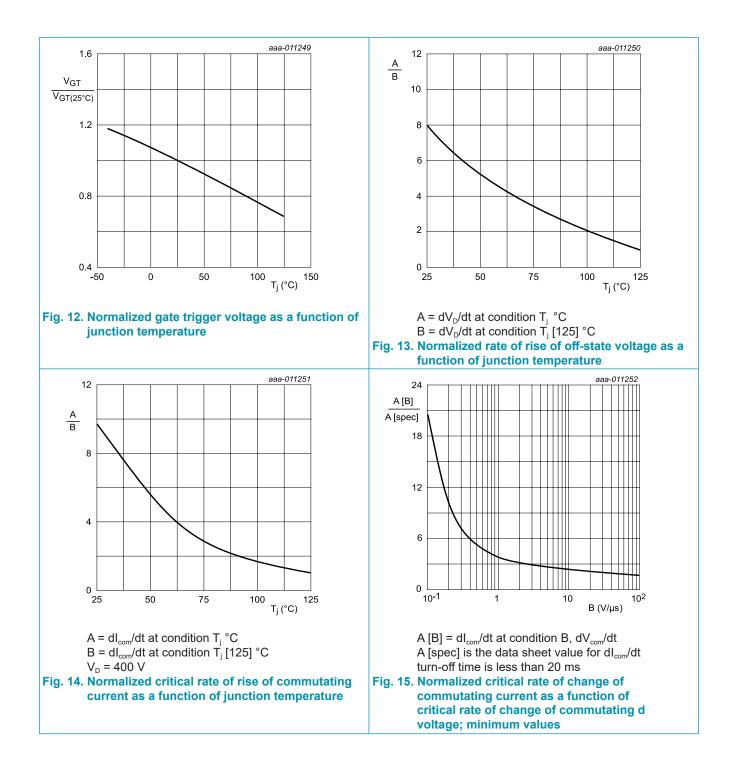


## **10. Characteristics**

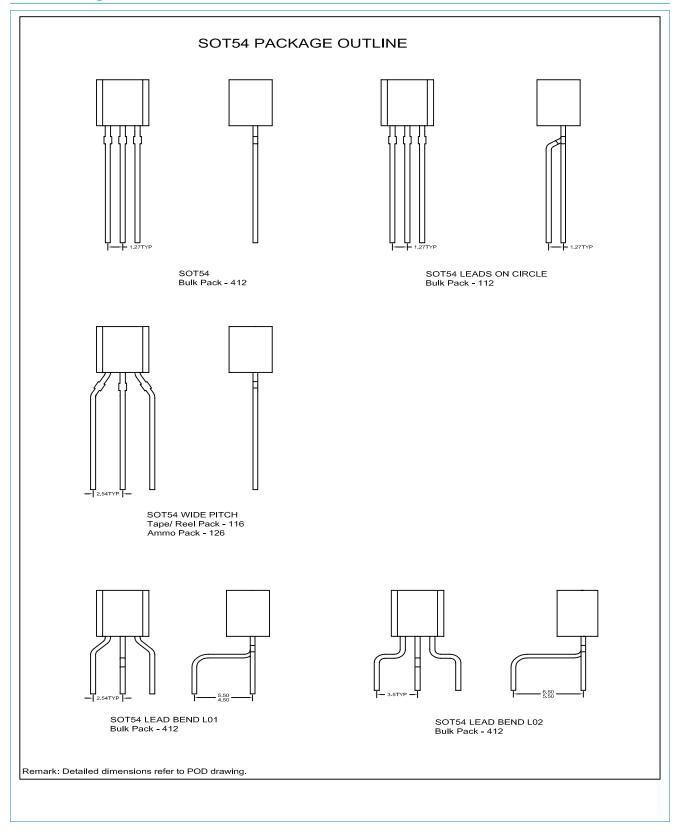
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	· · · · · · · · · · · · · · · · · · ·	·			
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ LD+ G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 8}$	1	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ LD- G-};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 8}$	1	-	10	mA
I <sub>L</sub>	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	25	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ LD- G-};$ $T_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 9}$	-	-	20	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	20	mA
V <sub>T</sub>	on-state voltage	$I_{T} = 1.1 \text{ A}; T_{j} = 25 \text{ °C}; Fig. 11$	-	-	1.3	V
$V_{\text{GT}}$	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 12	-	-	1	V
		$V_{\rm D}$ = 400 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C	0.15	-	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 800 V; T <sub>j</sub> = 25 °C	-	-	2	uA
		V <sub>D</sub> = 800 V; T <sub>j</sub> = 125 °C	-	-	0.2	mA
V <sub>CL</sub>	clamping voltage	$I_{CL} = 0.1 \text{ mA}; t_p = 1 \text{ ms}; T_j \le 25 \text{ °C};$	850	-	-	V
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 536 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit; Fig. 13	500	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 0.8$ A; $dV_{com}/dt = 20 \text{ V}/\mu s$ ; (snubberless condition); gate open circuit; Fig. 14; Fig. 15	0.5	-	-	A/ms

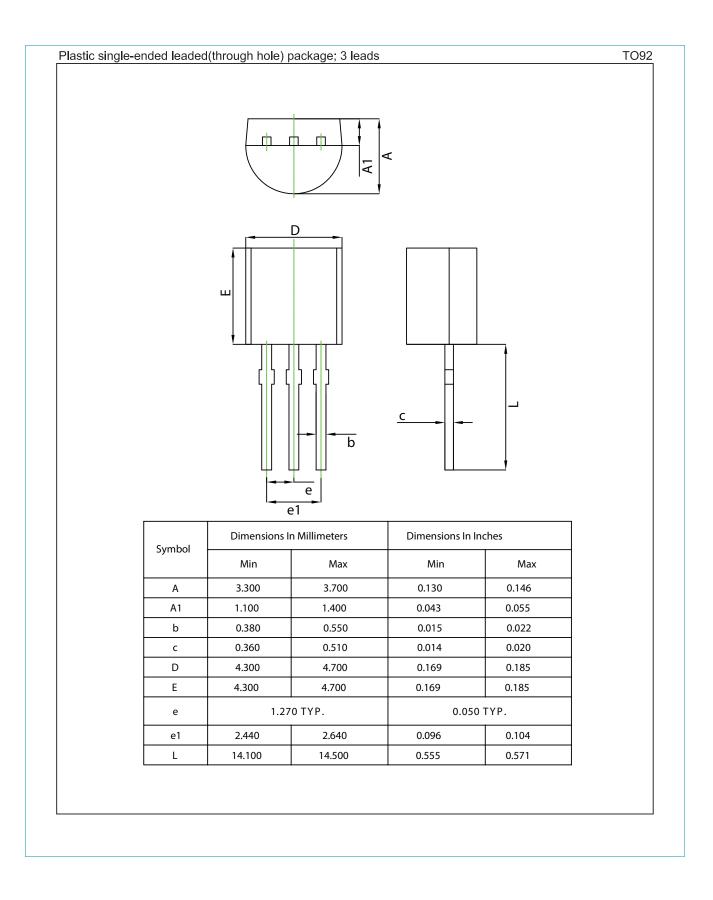


ACT108-800E AC Thyristor power switch



# 11. Package outline





# ACT108-800E

### 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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### **13. Contents**

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	3
9. Thermal characteristics	6
10. Characteristics	7
11. Package outline	10
12. Legal information	12
13. Contents	14

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